# 500 mA CMOS LDO Regulator

### Description

The CAT6219 is a 500 mA CMOS low dropout regulator that provides fast response time during load current and line voltage changes.

The quick-start feature allows the use of an external bypass capacitor to reduce the overall output noise without affecting the turn-on time of just  $150 \ \mu s$ .

With zero shutdown current and low ground current of 55  $\mu$ A typical, the CAT6219 is ideal for battery-operated devices with supply voltages from 2.3 V to 5.5 V. An internal under voltage lockout circuit disables the output at supply voltages under 2.15 V typical.

The CAT6219 offers 1% initial accuracy and low dropout voltage, 300 mV typical at 500 mA. Stable operation is provided with a small value ceramic capacitor, reducing required board space and component cost.

Other features include current limit and thermal protection.

The LDO is available in fixed and adjustable output in the low profile (1 mm max height) 5–lead TSOT23, 6–pad 1.5 mm x 1.5 mm WDFN and in the 6–pad 2 mm x 2 mm TDFN packages.

### Features

- Guaranteed 500 mA Peak Output Current
- Low Dropout Voltage of 300 mV Typical at 500 mA
- Stable with Ceramic Output Capacitor
- External 10 nF Bypass Capacitor for Low Noise
- Quick-start Feature
- Under Voltage Lockout
- No-load Ground Current of 55 µA Typical
- Full-load Ground Current of 85 µA Typical
- $\pm 1.0\%$  Initial Accuracy (V<sub>OUT</sub>  $\ge 2.0$  V)
- $\pm 2.0\%$  Accuracy Over Temperature (V<sub>OUT</sub>  $\ge 2.0$  V)
- "Zero" Current Shutdown Mode
- Fold-back Current Limit
- Thermal Protection
- 5-lead TSOT-23, 6-pad WDFN and TDFN Packages
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

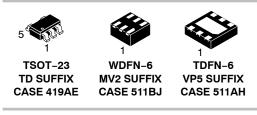
### Applications

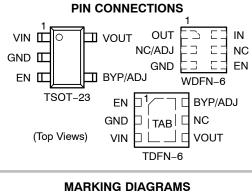
- Cellular Phones
- Battery-powered Devices
- Consumer Electronics

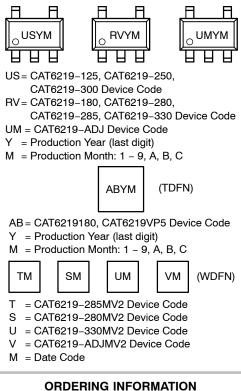


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See detailed ordering and shipping information in the package dimensions section on page 11 of this data sheet.

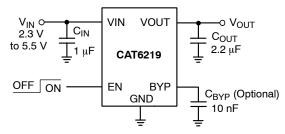


Figure 1. Typical Application Circuit

#### Table 1. PIN DESCRIPTIONS

Name	Function				
VIN	Supply voltage input.				
GND	Ground reference.				
EN	Enable input (active high); a 2.5 M $\Omega$ pull-down resistor is provided.				
BYP	Optional bypass capacitor connection for noise reduction and PSRR enhancing.				
ADJ	Adjustable input. Feedback pin connected to resistor divider.				
VOUT	LDO Output Voltage.				
TAB	To be connected to the ground plane on PCB				

### **Pin Function**

**VIN** is the supply pin for the LDO. A small 1  $\mu$ F ceramic bypass capacitor is required between the V<sub>IN</sub> pin and ground near the device. When using longer connections to the power supply, C<sub>IN</sub> value can be increased without limit. The operating input voltage range is from 2.3 V to 5.5 V.

#### Table 2. ABSOLUTE MAXIMUM RATINGS

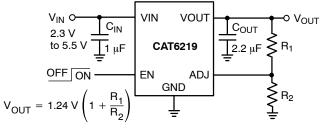


Figure 2. Adjustable Output LDO

**EN** is the enable control logic (active high) for the regulator output. It has a 2.5 M $\Omega$  pull-down resistor, which assures that if EN pin is left open, the circuit is disabled.

**VOUT** is the LDO regulator output. A small 2.2  $\mu$ F ceramic bypass capacitor is required between the VOUT pin and ground. For better transient response, its value can be increased to 4.7  $\mu$ F.

The capacitor should be located near the device. For the SOT23-5 package, a continuous 500 mA output current may turn-on the thermal protection. A 250  $\Omega$  internal shutdown switch discharges the output capacitor in the no-load condition.

**GND** is the ground reference for the LDO. The pin must be connected to the ground plane on the PCB.

**BYP** is the reference bypass pin. An optional  $0.01 \,\mu\text{F}$  capacitor can be connected between BYP pin and GND to reduce the output noise and enhance the PSRR at high frequency.

**ADJ** is the adjustable input pin for the adjustable LDO. The pin is connected to the resistor voltage divider.

Parameter	Rating	Unit
V <sub>IN</sub>	0 to 6.5	V
V <sub>EN</sub> , V <sub>OUT</sub>	–0.3 to V <sub>IN</sub> + 0.3	V
Junction Temperature, T <sub>J</sub>	+150	°C
Power Dissipation, P <sub>D</sub>	Internally Limited (Note 1)	mW
Storage Temperature Range, T <sub>S</sub>	-65 to +150	°C
Lead Temperature (soldering, 5 sec.)	260	°C
ESD Rating (Human Body Model)	3	kV

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### Table 3. RECOMMENDED OPERATING CONDITIONS (Note 2)

Parameter	Range	Unit
V <sub>IN</sub>	2.3 to 5.5	V
V <sub>EN</sub>	0 to V <sub>IN</sub>	V
Junction Temperature Range, T <sub>J</sub>	-40 to +125	°C
Package Thermal Resistance, θ <sub>JA</sub> SOT23-5 TDFN-6	235 206	°C/W

NOTE: Typical application circuit with external components is shown above.

1. The maximum allowable power dissipation at any  $T_A$  (ambient temperature) is  $P_{Dmax} = (T_{Jmax} - T_A)/\theta_{JA}$ . Exceeding the maximum allowable power dissipation will result in excessive die temperature, and the regulator will go into thermal shutdown.

2. The device is not guaranteed to work outside its operating rating.

#### Table 4. ELECTRICAL OPERATING CHARACTERISTICS (Note 3)

 $(V_{IN} = V_{OUT} + 1.0 \text{ V}, V_{EN} = \text{High}, I_{OUT} = 100 \ \mu\text{A}, C_{IN} = 1 \ \mu\text{F}, C_{OUT} = 2.2 \ \mu\text{F}$ , ambient temperature of 25°C (over recommended operating conditions unless specified otherwise). **Bold numbers** apply for the entire junction temperature range.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OUT-ACC</sub>	Output Voltage Accuracy	Initial accuracy for $V_{OUT} \ge 2.0 V$	-1.0		+1.0	%
		(Note 6)	-2.0		+2.0	
TC <sub>OUT</sub>	Output Voltage Temp. Coefficient			40		ppm/°C
$V_{R-LINE}$	Line Regulation	$V_{IN} = V_{OUT} + 1.0 V \text{ to } 5.5 V$	-0.2	±0.1	+0.2	%/V
			-0.4		+0.4	
V <sub>R-LOAD</sub>	Load Regulation	I <sub>OUT</sub> = 100 μA to 500 mA		1	1.5	%
					2	
V <sub>DROP</sub>	Dropout Voltage (Note 4)	I <sub>OUT</sub> = 500 mA		300	400	mV
					500	
I <sub>GND</sub>	Ground Current	I <sub>OUT</sub> = 0 μA		55	75	μΑ
					90	
		I <sub>OUT</sub> = 500 mA		85		
I <sub>GND-SD</sub>	Shutdown Ground Current	V <sub>EN</sub> < 0.4 V			1	μΑ
					2	
PSRR	Power Supply Rejection Ratio	f = 1 kHz, C <sub>BYP</sub> = 10 nF		64		dB
		f = 20 kHz, C <sub>BYP</sub> = 10 nF		54		
I <sub>SC</sub>	Output short circuit current limit	V <sub>OUT</sub> = 0 V		200		mA
T <sub>ON</sub>	Turn–On Time	C <sub>BYP</sub> = 10 nF		150		μs
e <sub>N</sub>	Output Noise Voltage (Note 5)	BW = 10 Hz to 100 kHz		45		μVrms
R <sub>OUT-SH</sub>	Shutdown Switch Resistance			250		Ω
R <sub>EN</sub>	Enable pull-down resistor			2.5		MΩ
V <sub>UVLO</sub>	Under voltage lockout threshold			2.15		V
ESR	C <sub>OUT</sub> equivalent series resistance		5		500	mΩ
V <sub>ADJ</sub>	Adjustable input voltage	I <sub>OUT</sub> = 100 μA	1.2	1.24	1.27	V

**ENABLE INPUT** 

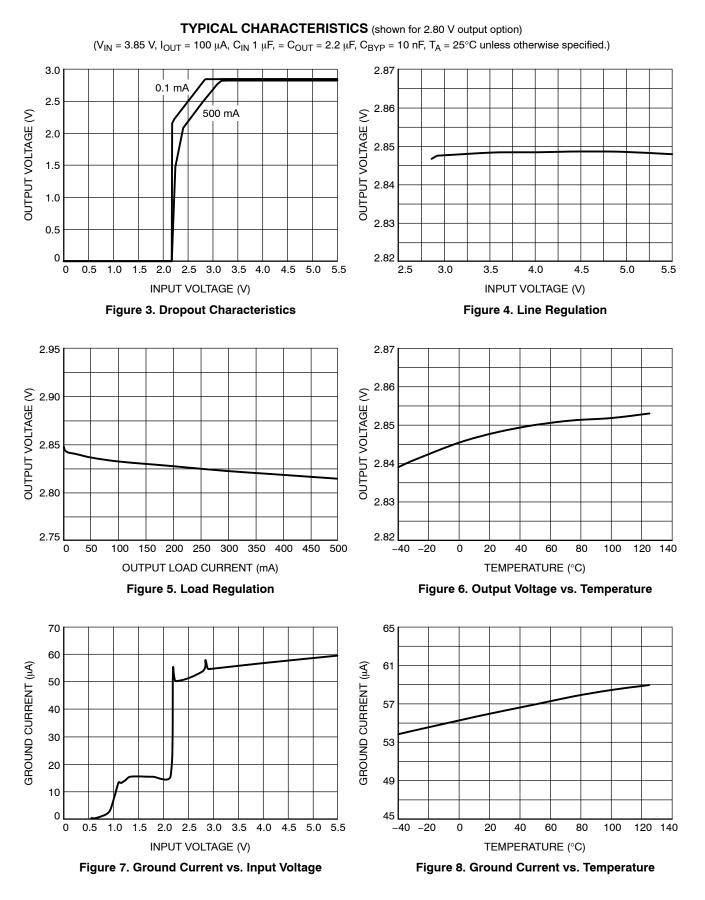
V <sub>HI</sub>	Logic High Level	V <sub>IN</sub> = 2.3 to 5.5 V	1.8			V
		$V_{IN}$ = 2.3 to 5.5 V, 0°C to +125°C junction temperature	1.6			
V <sub>LO</sub>	Logic Low Level	V <sub>IN</sub> = 2.3 to 5.5 V			0.4	V
I <sub>EN</sub>	Enable Input Current	V <sub>EN</sub> = 0.4 V		0.15	1	μΑ
		V <sub>EN</sub> = V <sub>IN</sub>		1.5	4	

### THERMAL PROTECTION

T <sub>SD</sub>	Thermal Shutdown		160	°C
T <sub>HYS</sub>	Thermal Hysteresis		10	°C

 Specification for 2.80 V output version unless specified otherwise.
Dropout voltage is defined as the input-to-output differential at which the output voltage drops 2% below its nominal value. During test, the input voltage stays always above the minimum 2.3 V.5. Specification for 1.8 V output version.

6. For V<sub>OUT</sub> < 2.0 V, the initial accuracy is  $\pm 2\%$  and across temperature  $\pm 3\%$ .





(V<sub>IN</sub> = 3.85 V, I<sub>OUT</sub> = 100  $\mu$ A, C<sub>IN</sub> 1  $\mu$ F, = C<sub>OUT</sub> = 2.2  $\mu$ F, C<sub>BYP</sub> = 10 nF, T<sub>A</sub> = 25°C unless otherwise specified.)

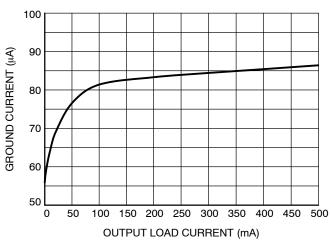
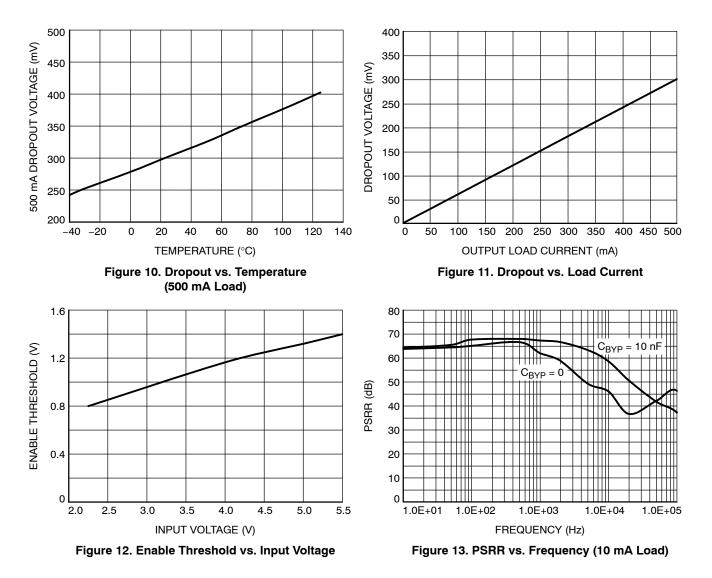
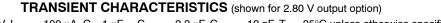


Figure 9. Ground Current vs. Load Current





(V<sub>IN</sub> = 3.85 V, I<sub>OUT</sub> = 100  $\mu$ A, C<sub>IN</sub> 1  $\mu$ F, = C<sub>OUT</sub> = 2.2  $\mu$ F, C<sub>BYP</sub> = 10 nF, T<sub>A</sub> = 25°C unless otherwise specified.)

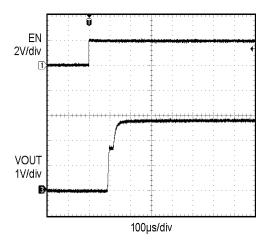


Figure 14. Enable Turn-on (100 µA Load)

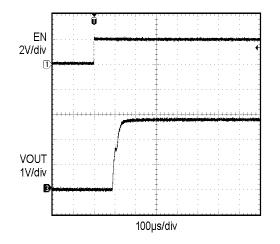


Figure 16. Enable Turn-on (500 mA Load)

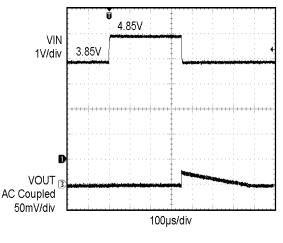


Figure 18. Line Transient Response (3.85 V to 4.85 V)

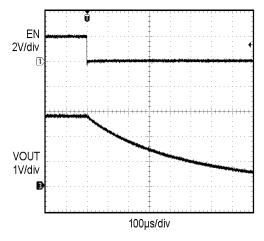
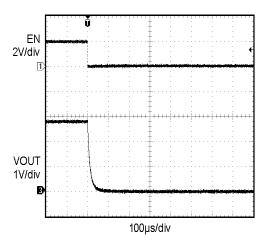
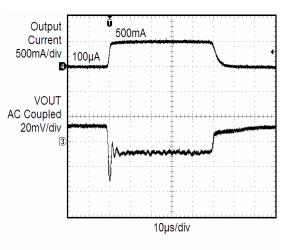
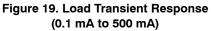


Figure 15. Enable Turn-off (100 µA Load)









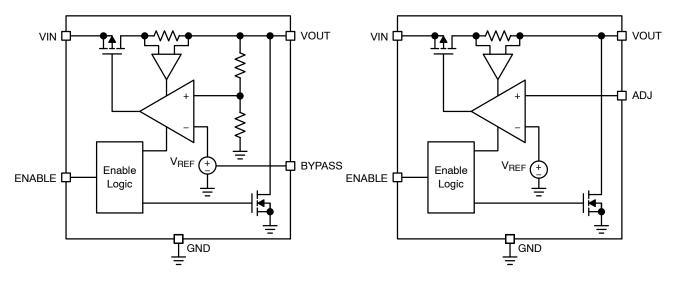
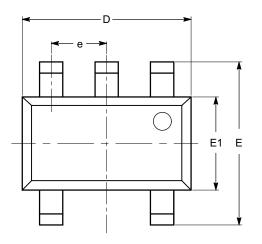


Figure 20. Block Diagram – Fixed Voltage

Figure 21. Block Diagram – Adjustable Voltage

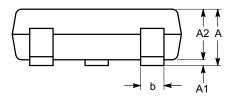
### PACKAGE DIMENSIONS

TSOT-23, 5 LEAD CASE 419AE-01 ISSUE O



SYMBOL MIN NOM MAX А 1.00 0.10 A1 0.01 0.05 A2 0.80 0.87 0.90 b 0.30 0.45 0.20 0.12 0.15 С D 2.90 BSC Е 2.80 BSC E1 1.60 BSC е 0.95 TYP L 0.30 0.40 0.50 L1 0.60 REF 0.25 BSC L2 θ 0° 8°

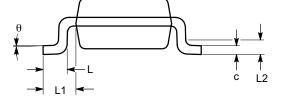
TOP VIEW



SIDE VIEW

#### Notes:

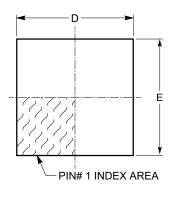
- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-193.

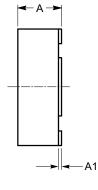


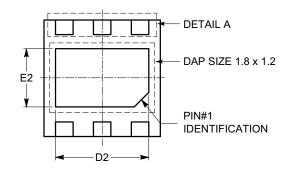
END VIEW

### PACKAGE DIMENSIONS

TDFN6, 2x2 CASE 511AH-01 ISSUE A







TOP VIEW

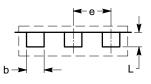


**BOTTOM VIEW** 

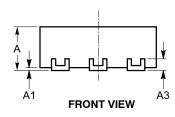
SYMBOL	MIN NOM		MAX		
А	0.70	0.75	0.80		
A1	0.00 0.02 0		0.05		
A3	0.20 REF				
b	0.25	0.25 0.30			
D	1.90	2.00	2.10		
D2	1.50 1.60 1.7				
E	1.90 2.00 2.1				
E2	0.90 1.00 1		1.10		
e	0.65 TYP				
L	0.15 0.25 0.3				

#### Notes:

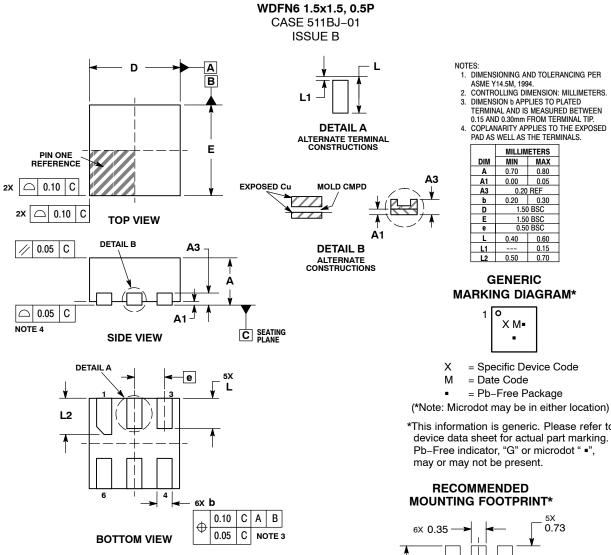
(1) All dimensions are in millimeters.
(2) Complies with JEDEC standard MO-229.



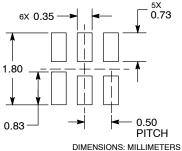
DETAIL A



### PACKAGE DIMENSIONS



\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •",



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### **ORDERING INFORMATION** (Notes 7 – 9)

Device Order Number	Specific Device Marking	Package Type	V <sub>OUT</sub> Voltage (V)	Lead Finish	Shipping (Note 10)
CAT6219-125TDGT3	US		1.25		
CAT6219-180TDGT3	RV		1.80		
CAT6219-250TDGT3	US		2.50		
CAT6219-280TDGT3	RV	T007 00 5	2.80		
CAT6219-285TDGT3	RV	TSOT-23-5	2.85		Tape & Reel, 3,000 Units / Reel
CAT6219-300TDGT3	US		3.00		
CAT6219-330TDGT3	RV		3.30	NiPdAu	
CAT6219ADJTD-GT3	UM		Adjustable		
CAT6219ADJVP5GT4	AF		Adjustable		
CAT6219180VP5GT4	AB	TDFN-6 (2.0 x 2.0)	1.80		Tape & Reel, 4,000 Units / Reel
CAT6219VP5330GT4	AB	()	3.30		
CAT6219-280MV2T3	S		2.80		
CAT6219-285MV2T3	Т	WDFN-6	2.85		
CAT6219-330MV2T3	U	(1.5 x 1.5)	3.30	1	Tape & Reel, 3,000 Units / Reel
CAT6219ADJMV2-T3	V	1	Adjustable	1	

7. All packages are RoHS-compliant (Lead-free, Halogen-free).

8. The standard lead finish is NiPdAu pre-plated (PPF) lead frames.

9. For other voltage options, please contact your nearest ON Semiconductor Sales office.

10. For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

11. For detailed information and a breakdown of device nomenclature and numbering systems, please see the ON Semiconductor Device Nomenclature document, TND310/D, available at <u>www.onsemi.com</u>

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